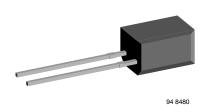
Vishay Semiconductors



Silicon PIN Photodiode, RoHS Compliant



FEATURES

Package type: leaded



• Dimensions (in mm): 5 x 4 x 6.8

• Radiant sensitive area (in mm²): 7.5

· High radiant sensitivity

Daylight blocking filter matched with 940 nm emitters

• Fast response times

• Angle of half sensitivity: $\varphi = \pm 65^{\circ}$

 Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS

DESCRIPTION

BPW41N is a PIN photodiode with high speed and high radiant sensitivity in a black, side view plastic package with daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

APPLICATIONS

- · High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSALxxxx series IR emitters

PRODUCT SUMMARY			
COMPONENT	I _{ra} (μΑ)	φ (deg)	λ _{0.5} (nm)
BPW41N	45	± 65	870 to 1050

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW41N	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	Side view	

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	60	V
Power dissipation	T _{amb} ≤ 25 °C	P _V	215	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R_{thJA}	350	K/W

Note

T_{amb} = 25 °C, unless otherwise specified



Silicon PIN Photodiode, RoHS Compliant Vishay Semiconductors

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 100 μA, E = 0	$V_{(BR)}$	60			V
Reverse dark current	V _R = 10 V, E = 0	I _{ro}		2	30	nA
Diada sanaitana	V _R = 0 V, f = 1 MHz, E = 0	C _D		70		pF
Diode capacitance	V _R = 3 V, f = 1 MHz, E = 0	C _D		25	40	pF
Open circuit Voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK_Vo		- 2.6		mV/K
Short circuit current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	l _k		38		μΑ
Temperature coefficient of I _k	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{lk}		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \ V_R = 5 \text{ V}$	I _{ra}	43	45		μΑ
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		λ_{p}		950		nm
Range of spectral bandwidth		λ _{0.5}		870 to 1050		nm
Noise equivalent power	$V_R = 10 \text{ V}, \lambda = 950 \text{ nm}$	NEP		4 x 10 ⁻¹⁴		W/√ Hz
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _r		100		ns
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _f		100		ns

Note

T_{amb} = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

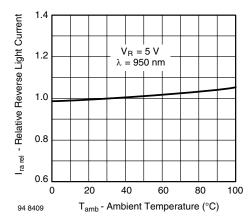


Fig. 1 - Relative Reverse Light Current vs. Ambient Temperature

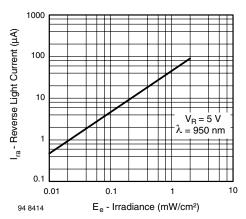


Fig. 2 - Reverse Light Current vs. Irradiance

Vishay Semiconductors

Silicon PIN Photodiode, RoHS Compliant



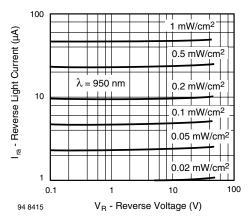


Fig. 3 - Reverse Light Current vs. Reverse Voltage

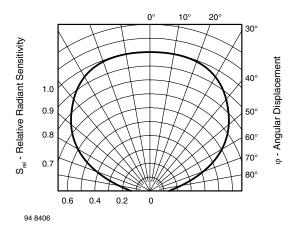


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

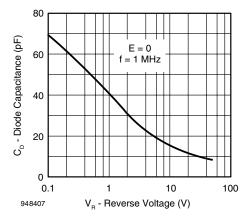


Fig. 4 - Diode Capacitance vs. Reverse Voltage

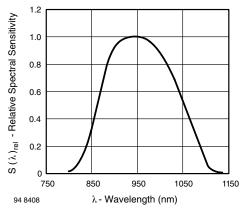
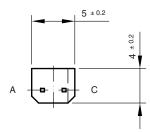


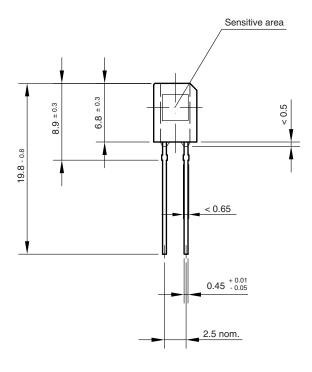
Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

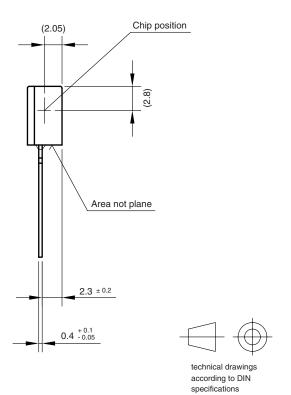


Silicon PIN Photodiode, RoHS Compliant Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters







Drawing-No.: 6.544-5108.01-4

Issue:1; 01.07.96

96 12195



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Photodiodes category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

LTR-526AD OED-SP-7L LTR-536AB 67-21SYGC-S349-TR8 SFH 2200 A01 HFD3081-108-XBA BPW 34 S E9601 SFH 2713 SFH 2703
LTR-546AD BPV23FL BPW 34 FAS BPW 34 FS IG17X1000S4I IG22X250S4I VTD205H VTD205KH VTP1232FH VTP4085H SFH
2400 OP913WSL OPF794 PD70-01C/TR7 LTR-536AD VTP8651H VTD206KH VTB1013H BPV23NF OP905 LTR-516AD BPW 34
FS-Z VTD34FH QSB34CGR SFH 2500 FA SFH 213 FA PD15-22C/TR8 VEMD5510C SFH 2200 VEMD5510CF SAH230M SAH230M2
SAH500M2 MTAPD-07-010 BP 104 FS BPV22F-AS12 BPW 21 BPW 34 SR-Z BPX 65 HSDL-5400#011 BPW 34 FASR